

1962nm DFB Tunable Laser Diode for HBr Sensing



Description

The PL-DFB-1962-A1 1962nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed 14 pin butterfly package with TEC and PD Built in.

Features

- Narrow Linewidth < 2MHz
- Excellent wavelength control and stability
- Industry Standard 14 pin Butterfly package
- Mode-Hop free tuning
- Excellent reliability
- Customer specific wavelengths available

Application

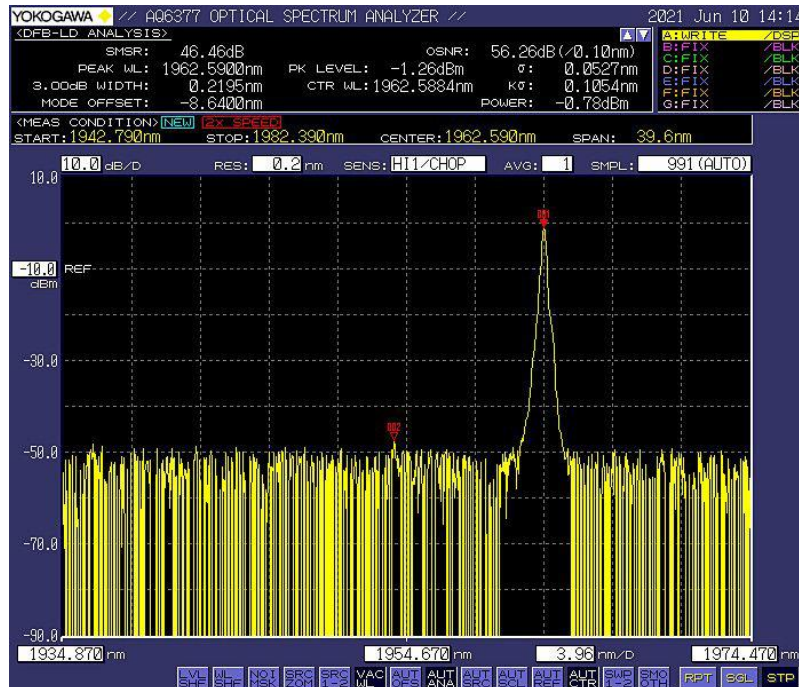
- Tunable diode laser absorption spectroscopy
- HBr Monitoring

Laser Specifications

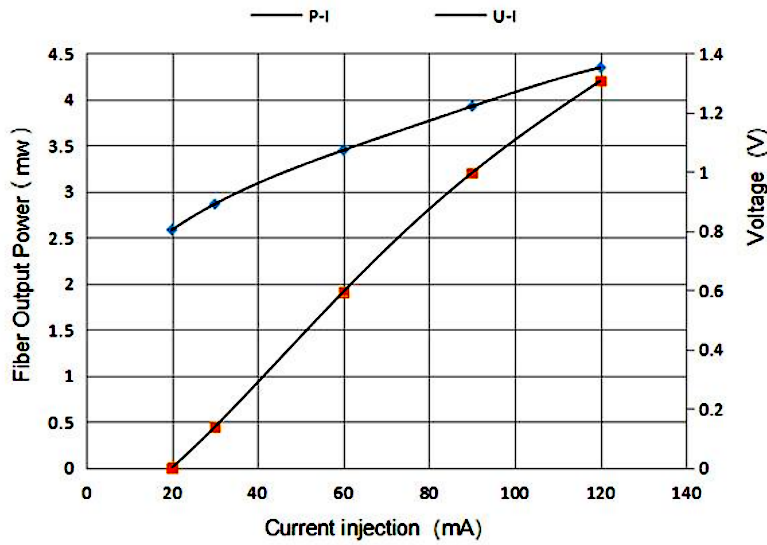
Electrical/Optical Characteristics(Tsub=25°C, CW bias unless stated otherwise)

Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	λ	1961	1962	1963	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	I _{th}		20	30	mA
Operating Current	I _{op}		80	120	mA
Chip output Power	P _f	4	5	6	mW
Quantum Efficiency	η	0.08	0.12		mW/mA
Current Tuning Coefficient	$\Delta\lambda / \Delta I$		0.015		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda / \Delta T$		0.12		nm/K
Forward Voltage	V _f		1.3	2	V
Thermistor Resistance	R _T	9.5	10	10.5	K Ω
Thermistor Temp. Coefficient			-4.4		%/°C
Connector	FC/APC				

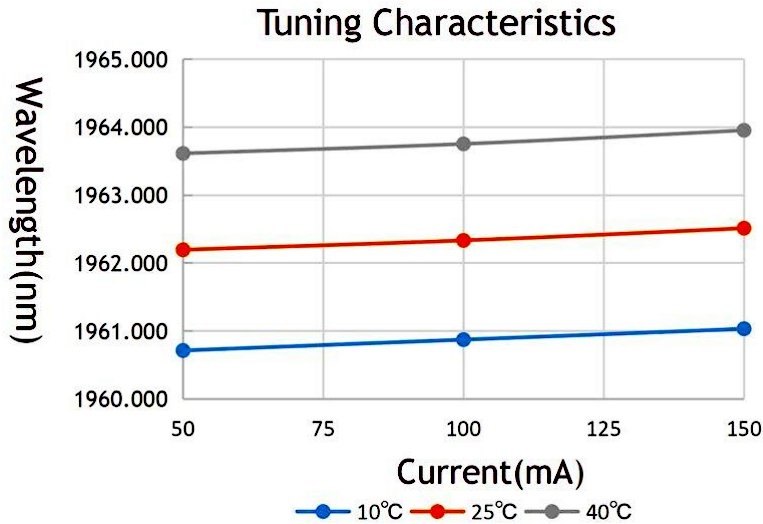
Spectrum



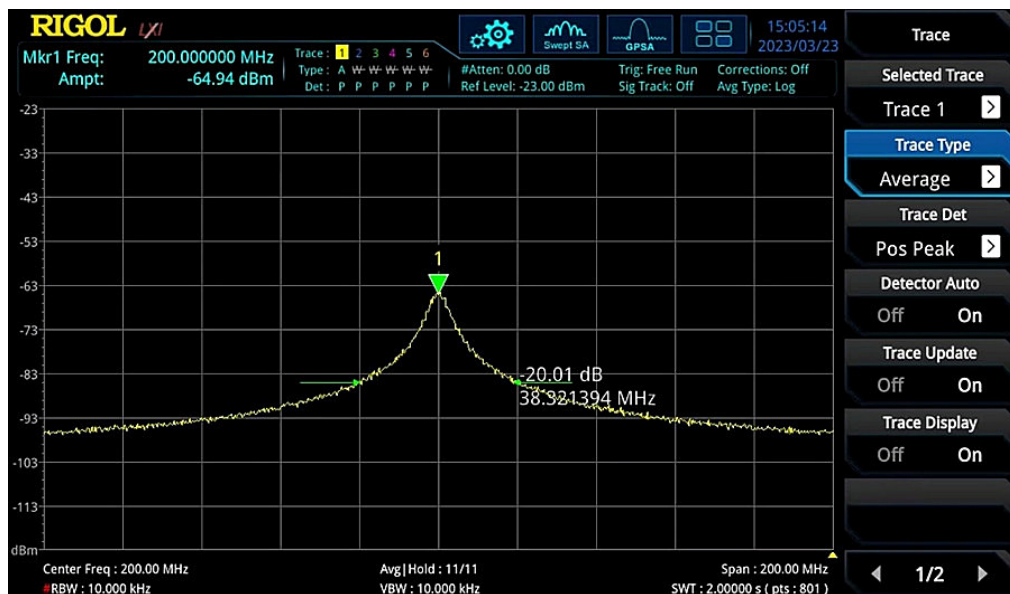
L-I Curve



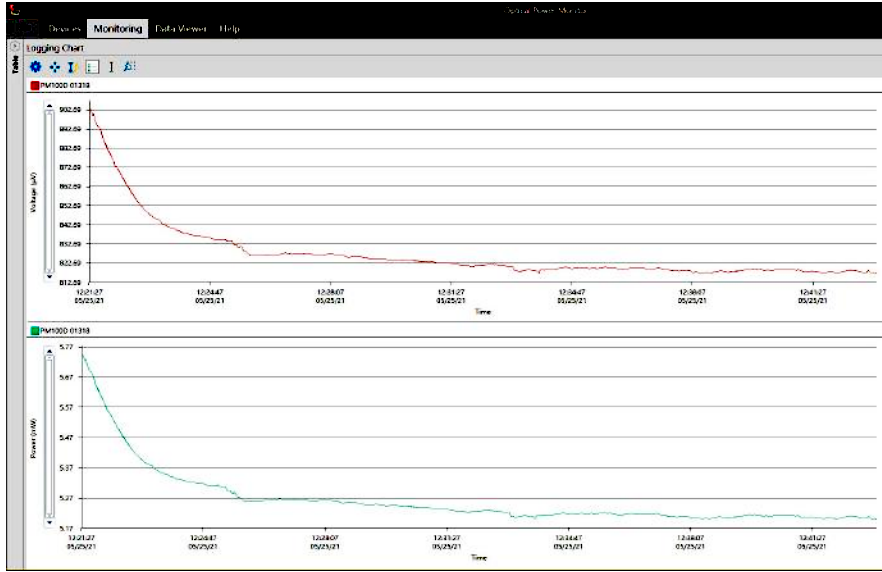
Tuning Characteristics



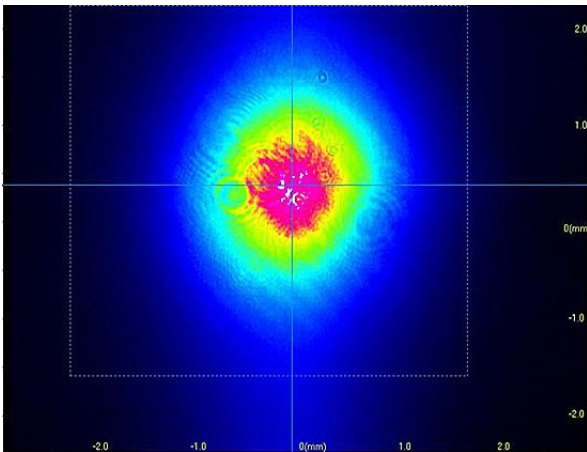
Power Stability



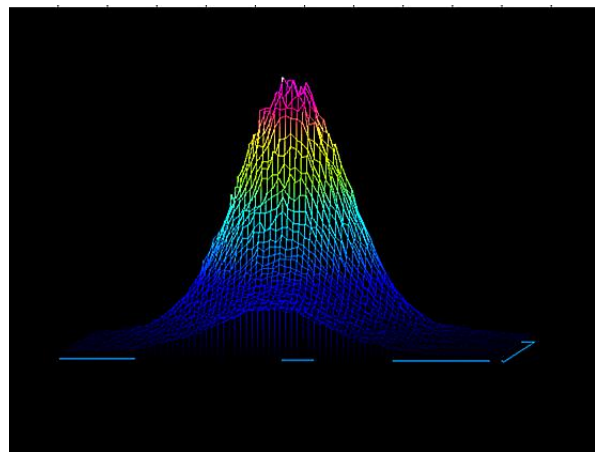
Power Stability



Beam Quality

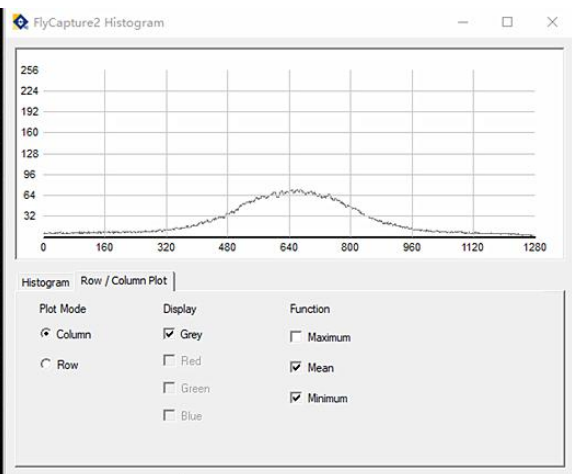
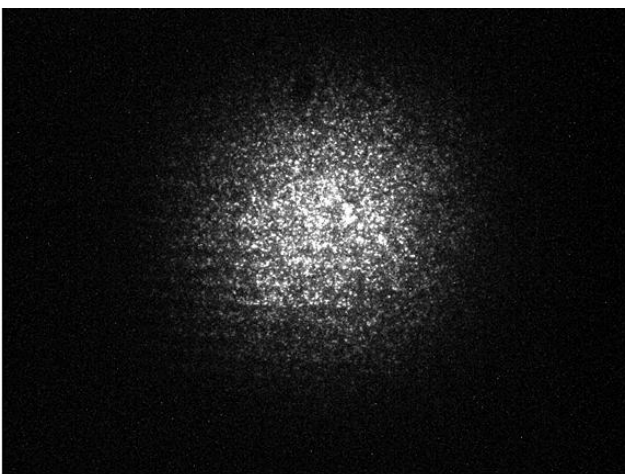


2D

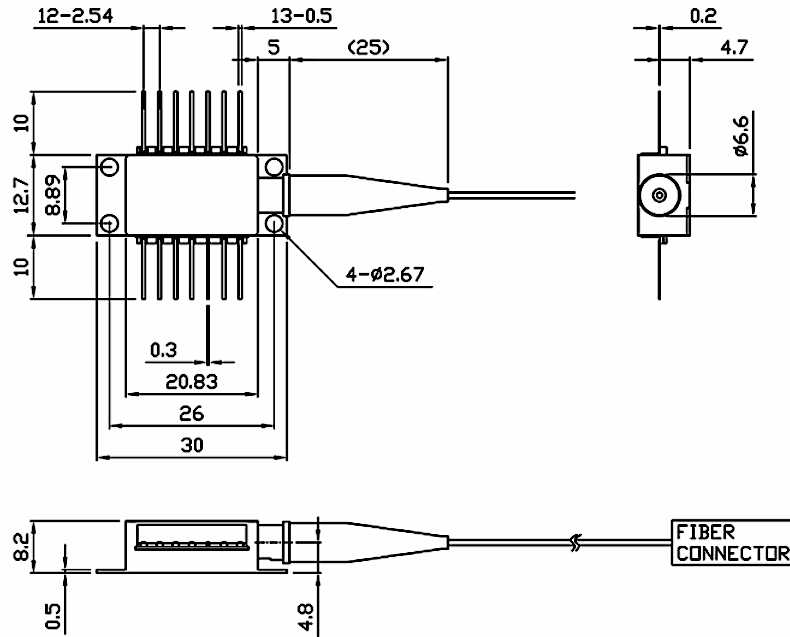


3D

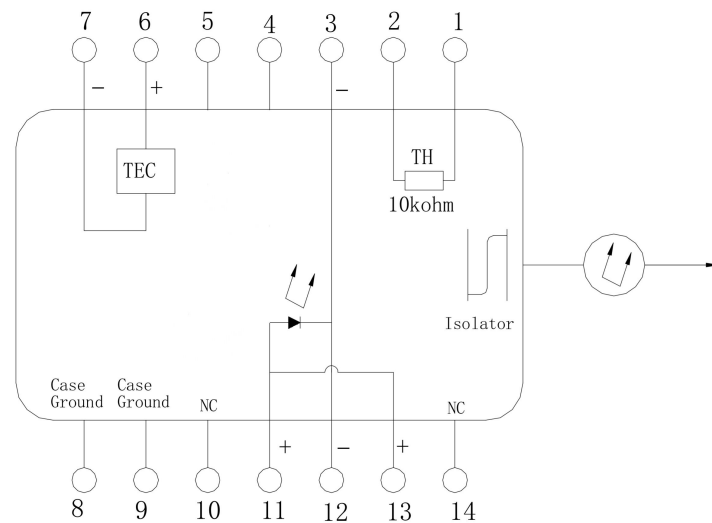
Camera Analysis



Package Size



Pin definition

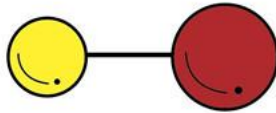
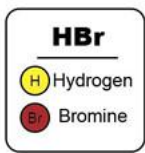


PIN#	Function	PIN#	Function
1	Thermistor	8	Case Ground
2	Thermistor	9	Case Ground
3	Laser Cathode(-)	10	NC
4	NC	11	Laser Anode (+)
5	NC	12	Laser Cathode (-)
6	TEC (+)	13	Laser Anode (+)
7	TEC (-)	14	NC

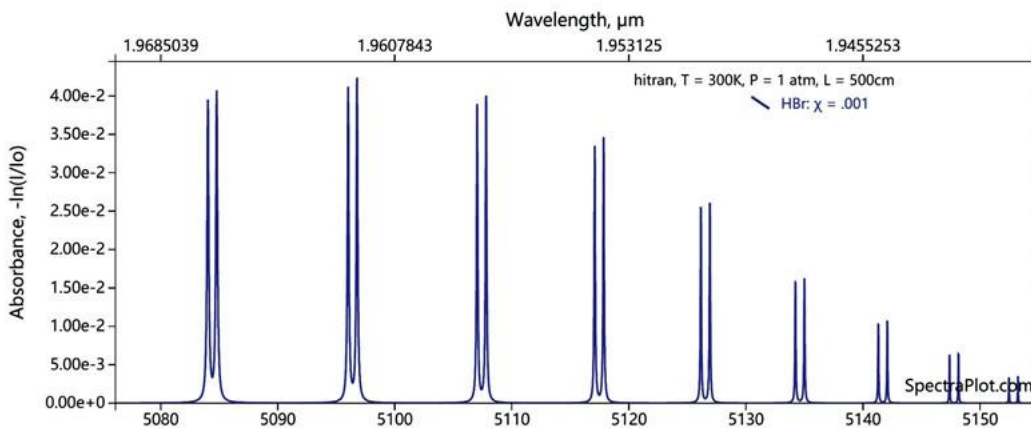
Absolute Maximum Ratings

Item	Unit	Min	Typ	Max
Case Temperature	°C	-5	25	70
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	100	150
Forward Voltage	V	0.8	1.2	1.8
TEC Current	A	-	-	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage (PD)	V	-	-	20

HBr



TDLAS: 1950/1962nm



Ordering Info

PL-DFB-□□□□-☆-A8▽-XX

□□□□: Wavelength

1390: 1390nm

1512: 1512nm

1567: 1567nm

1570: 1570nm

1653.7: 1653.7nm

1962: 1962nm

2327: 2327nm

☆: Output Power

A: 5mW

B: 10mW

▽: Wavelength Tolerance

1: ±1nm

2: ±2nm

XX: Fiber and Connector Type

SA=SMF-28E+ FC/APC

SP=SMF-28E+ FC/PC

PP=PM Fiber+ FC/PC

PA=PM Fiber+ FC/APC